Analog Power AM5931P

P-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

battery-powered products such as computers,	-30	$0.130 @ V_{GS} = -4.5$
printers, PCMCIA cards, cellular and cordless		0.130 @ V _{GS} = -4.3
telephones.		
	CF1206-8	

- $\hbox{$ \stackrel{\bullet}{$}$ Low $r_{DS(on)}$ provides higher efficiency and extends battery life }$
- Low thermal impedance copper leadframe CF1206-8 saves board space
- Fast switching speed
- High performance trench technology

	CF1206-8				
	Top View		S ₁		S_2
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G1 ⊞	2 7	D,	$G_1 \hookrightarrow \downarrow$	(G₂ ~
S2IT	3 6	Бο.	[ļ'

 $r_{DS(on)}$ (OHM)

 $0.084 @ V_{GS} = -10V$

 $I_{D}(A)$

-3.1

-2.5

P-Channel MOSFET

PRODUCT SUMMARY

 $V_{DS}(V)$

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Maximum	Units		
Drain-Source Voltage			-30	V		
Gate-Source Voltage	V_{GS}	±20	V			
	$T_A=25^{\circ}C$. т_	-3.1			
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-2.5	A		
Pulsed Drain Current ^b	I_{DM}	-10				
Continuous Source Current (Diode Conduction) ^a		I_S	±1.6	A		
D D: : .: à	T _A =25°C	D	1.15	337		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	0.7		W		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C		

G2 🗖 4

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Тур	Max				
Mariana Indiana da Ambinda	t <= 10 sec	R_{thJA}	93	110	0CM		
Maximum Junction-to-Ambient ^a	Steady State		130	150	°C/W		

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

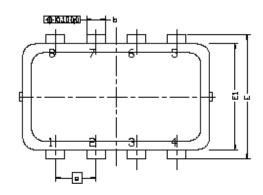
SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)								
Danamatan	Cymbol	Test Conditions	Limits			Unit		
Parameter	Symbol	Test Conditions	Min		Max	Umi		
Static								
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1.00					
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = +/-20 \text{ V}$			±100	nA		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA		
Zero Gate Voltage Drain Current	DSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	uA_		
On-State Drain Current ^A	$I_{D(on)}$	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-3			A		
D : G . C . D : A	r	$V_{GS} = -10 \text{ V}, I_D = -2.5 \text{ A}$	$-10 \text{ V}, I_D = -2.5 \text{ A}$		0.084			
Drain-Source On-Resistance ^A	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -1.2 \text{ A}$			0.130	Ω		
Forward Tranconductance ^A	${f g}_{ m fs}$	$V_{DS} = -5 \text{ V}, I_{D} = -2.5 \text{ A}$		3		S		
Diode Forward Voltage	V_{SD}	$I_S = -1.6 \text{ A}, V_{GS} = 0 \text{ V}$		-0.70		V		
Dynamic ^b	-		•			<u>-</u>		
Total Gate Charge	Q_{g}	V - 5 V V - 45 V		6.0				
Gate-Source Charge	Q_{gs}	$V_{DS} = -5 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -2.5 \text{ A}$		0.80		пC		
Gate-Drain Charge	Q_{gd}	$I_D = -2.3 A$		1.30		1		
Turn-On Delay Time	$t_{d(on)}$			6.5				
Rise Time	$t_{\rm r}$	$V_{DD} = -5 \text{ V}, R_L = 5 \text{ OHM},$		20		,,,		
Turn-Off Delay Time	$t_{ m d(off)}$	$V_{GEN} = -4.5 \text{ V}, R_{G} = 6 \text{ OHM}$		31		ns		
Fall-Time	$t_{ m f}$			21				

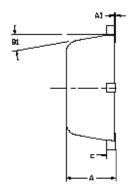
Notes

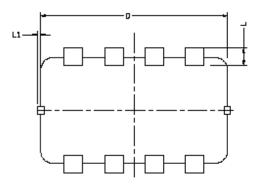
- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Package Information







DIM.	MULLIMETERS			INCHES			
7311.11	MEN	NI T	MAX	MIM	NOM	MAX	
Α	Q700	0.80	מספגם	0.0276	0.0315	0.0334	
Al	딦	-	0,05	0.000	-	0.002	
b	0.24	0.30	1.35	0.009	0.012	0.014	
C	90,0	0.152	1.25	0.003	0,006	0.010	
D	3.00 BSC			0.118 BSC			
E	Ē	OD B5	Ç	QO79 BSC			
E1	1.70 BSC			Q0 67 BSC			
6	0.65 BSC			Q026 BSC			
L	¢.20	0.275	0.400	0,000	0.011	0.0157	
Li	Ď		0.108	Ď		0.004	
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